

6-Unit 320mA Transistor Array

T-52-07

IR2C24/IR2C24N

# IR2C24/IR2C24N 6-Unit 320mA Transistor Array

## ■ Description

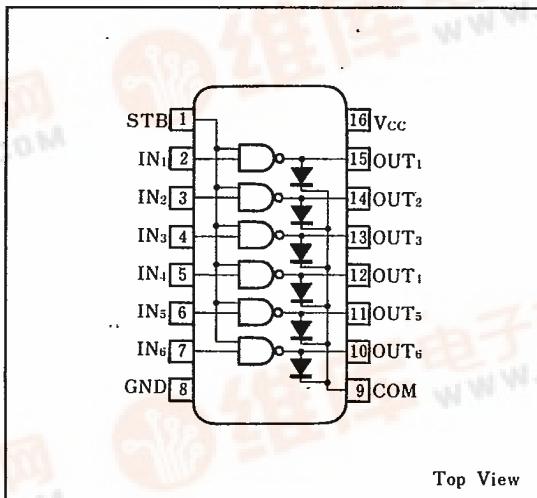
The IR2C24/IR2C24N is a 6-circuit driver IC which can be used for driving printer, relays, LEDs and lamps. The strobe pin enables all circuits to cut off without external transistors.

Clamping diodes protect output transistors from counter electromotive force.

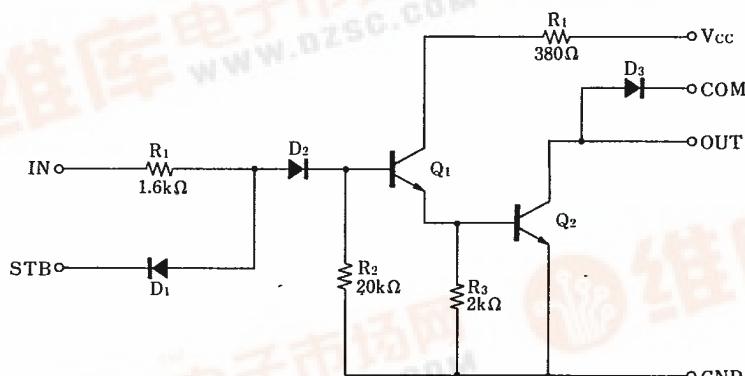
## ■ Features

1. With strobe pin
2. With clamping diodes
3. Output breakdown voltage  $BV_{CEO}=20V(\text{MAX.})$
4. Output current  $>320\text{mA}(\text{MAX.})$
5. 16-pin dual-in-line package(IR2C24)  
16-pin small-outline package(IR2C24N)

## ■ Pin Connections



## ■ Equivalent Circuit



SHARP

6-Unit 320mA Transistor Array

IR2C24/IR2C24N

T-52-07

**Absolute Maximum Ratings**

Parameter	Symbol	Condition		Rating	Unit
Supply voltage	V <sub>CC</sub>			10	V
Input voltage	V <sub>IN</sub>			-25~+20	V
Output current	I <sub>OUT</sub>	Each circuit		320	mA
Output breakdown voltage	BV <sub>CEO</sub>			20	V
Strobe input voltage	V <sub>IN</sub> STB			20	V
Clamp diode reverse voltage	V <sub>R</sub>	For clamp diode		20	V
Clamp diode surge current	I <sub>surge</sub>	For clamp diode		320	mA
Power dissipation	P <sub>D</sub>	T <sub>a</sub> ≤25°C	IR2C24	1,470	mW
			IR2C24N	600	
P <sub>D</sub> derating ratio	ΔP <sub>D</sub> /°C	T <sub>a</sub> >25°C	IR2C24	14.7	mW/°C
			IR2C24N	6	
Operating temperature	T <sub>opr</sub>			-20~+75	°C
Storage temperature	T <sub>stg</sub>			-55~+150	°C

**Recommend Operating Conditions**

(Ta = -20~+75°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	V <sub>CC</sub>		3		8	V
Max. output voltage	V <sub>CED</sub>				20	V
Output current	I <sub>OUT</sub>	V <sub>CC</sub> =6.5V, at 25% duty or less			300	mA
		V <sub>CC</sub> =6.5V, at 65% duty or less			150	
Input "High" voltage	V <sub>IH</sub>	I <sub>OUT</sub> =300mA	3.2			V
Input "Low" voltage	V <sub>IL</sub>	I <sub>OUT</sub> (Leak)=50 μA			0.7	V
Strobe input "High" voltage	V <sub>IH</sub> STB	For strobe pin	2.4			V
Strobe input "Low" voltage	V <sub>IL</sub> STB	For strobe			0.2	V

**Electrical Characteristics**(V<sub>CC</sub>=8V, Ta=-20~+75°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Output voltage	V <sub>CEO</sub>	V <sub>IN</sub> =3.2V, V <sub>IN</sub> STB=0.2V, I <sub>OUT</sub> =100 μA			20	V
On state output voltage	V <sub>OUT</sub> ON <sub>1</sub>	V <sub>IN</sub> =3V V <sub>IN</sub> STB=2.4V	V <sub>CC</sub> =6.5V, I <sub>OUT</sub> =300mA	0.6	1.0	V
			V <sub>CC</sub> =6.5V, I <sub>OUT</sub> =250mA	0.5	0.85	
			V <sub>CC</sub> =3V, I <sub>OUT</sub> =120mA	0.3	0.5	
Input current	I <sub>IN</sub>	V <sub>IN</sub> =3.2V, V <sub>IN</sub> STB=2.4V			1.4	mA
Input reverse leakage current	I <sub>IR</sub>	V <sub>IN</sub> =-25V			-20	μA
Strobe input current	I <sub>IN</sub> STB	For strobe pin, V <sub>IN</sub> =3.2V(All input), V <sub>IN</sub> STB=0.2V		-7.9		mA
Strobe input reverse leakage current	I <sub>IR</sub> STB	For strobe pin, V <sub>IN</sub> =0V, V <sub>IN</sub> STB=20V			20	μA
Clamp diode forward voltage	V <sub>F</sub>	For clamp diode, I <sub>surge</sub> =320mA		1.4	2.4	V
Clamp diode reverse voltage	V <sub>R</sub>	For clamp diode, I <sub>R</sub> =100 μA	20	40		V
Supply current	I <sub>CC</sub>	V <sub>IN</sub> =3.2V(All input), V <sub>IN</sub> STB=2.4V			200	mA
DC current amplitude	h <sub>FE</sub>	V <sub>CC</sub> =6.5V, V <sub>CEO</sub> =4V, I <sub>OUT</sub> =300mA, Ta=25°C	1,000			